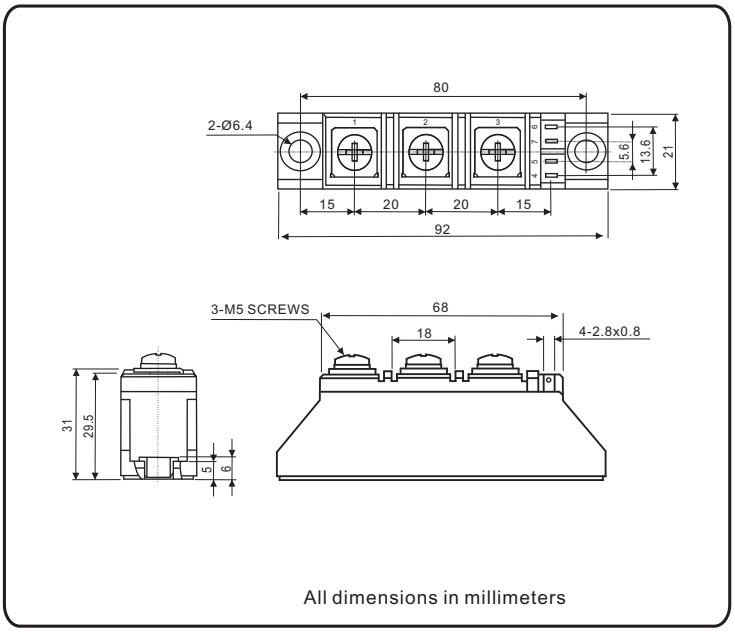
Thyristor/Diode and Thyristor/Thyristor, 90A
(ADD-A-PAK Power Modules)

ADD-A-PAK



All dimensions in millimeters

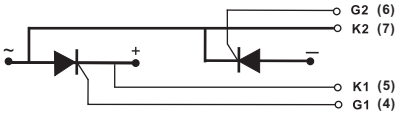
FEATURES

- High voltage
- Electrically isolated by DBC ceramic (Al_2O_3)
- 3000 V_{RMS} isolating voltage
- Industrial standard package
- High surge capability
- Glass passivated chips
- Modules uses high voltage power thyristor/diodes in two basic configurations
- Simple mounting
- UL approved file E320098
- Compliant to RoHS
- Designed and qualified for multiple level

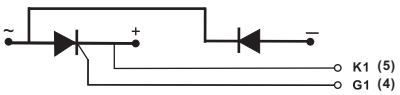
RoHS COMPLIANT

APPLICATIONS

- DC motor control and drives
- Battery charges
- Welders
- Power converters
- Lighting control
- Heat and temperature control



NKT



NKH

PRODUCT SUMMARY	
$I_{T(AV)}$	90 A

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUE	UNITS
$I_{T(AV)}$	85 °C	90	A
$I_{T(RMS)}$	85 °C	141	A
I_{TSM}/I_{FSM}	50 Hz	2000	
	60 Hz	2100	
I^2t	50 Hz	20	kA^2s
	60 Hz	18.3	
$I^2\sqrt{t}$		200	$kA^2\sqrt{s}$
V_{DRM} / V_{RRM}	Range	400 to 1600	V
T_J	Range	-40 to 125	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V_{RRM}/V_{DRM}, MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM}/V_{DSM}, MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM}/I_{DRM} AT 125 °C mA
NKT90..A NKH90..A	04	400	500	10
	08	800	900	
	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUE	UNITS
Maximum average on-state current at case temperature	$I_{T(AV)}$	180° conduction, half sine wave ,50Hz			90	A
					85	°C
Maximum RMS on-state current	$I_{T(RMS)}$	180° conduction, half sine wave ,50Hz ,T_C = 85°C			141	A
Maximum peak, one-cycle, on-state non-repetitive surge current	I_{TSM}	t = 10 ms	No voltage reapplied	Sine half wave, initial T_J = T_J maximum	2000	
		t = 8.3 ms			2100	
Maximum I^2t for fusing	I^2t	t = 10 ms			20	kA^2s
		t = 8.3 ms			18.3	
		t = 10 ms	100%V_{RRM} reapplied		14	
		t = 8.3 ms			12.8	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 ms to 10 ms, no voltage reapplied			200	$kA^2\sqrt{s}$
Maximum on-state voltage drop	V_{TM}	I_{TM} = 270A , T_J = 25 °C, 180° conduction			1.6	V
Maximum forward voltage drop	V_{FM}	I_{FM} = 270A , T_J = 25 °C, 180° conduction			1.3	
Maximum holding current	I_H	Anode supply = 6 V,resistive load T_J = 25 °C			150	mA
Maximum latching current	I_L	Anode supply = 6 V resistive load, T_J = 25 °C			400	

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak reverse and off-state leakage current	I_{RRM} I_{DRM}	T_J = 125 °C	10	mA
RMS isolation Voltage	V_{ISO}	50 Hz, circuit to base, all terminals shorted	2500 (1min) 3000 (1s)	V
Critical rate of rise of off-state voltage	dV/dt	T_J = T_J maximum, exponential to 67 % rated V_{DRM}	500	V/µs

TRIGGERING					
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**VALUES**	**UNITS**
Maximum peak gate power	P_{GM}	$t_p \le 5$ ms, $T_J = T_J$ maximum		10	W
Maximum average gate power	$P_{G(AV)}$	f = 50 Hz, $T_J = T_J$ maximum		3	
Maximum peak gate current	I_{GM}	$t_p \le 5$ ms, $T_J = T_J$ maximum		3	A
Maximum peak negative gate voltage	$-V_{GT}$			10	V
Maximum required DC gate voltage to trigger	V_{GT}	T_J = 25 °C	Anode supply = 6 V, resistive load; R_a = 1 Ω	0.7~1.6	
Maximum required DC gate current to trigger	I_{GT}			20~100	mA
Maximum gate voltage that will not trigger	V_{GD}	$T_J = T_J$ maximum, 66.7% V_{DRM} applied		0.25	V
Maximum gate current that will not trigger	I_{GD}			10	mA
Maximum rate of rise of turned-on current	dI/dt	T_J = 25°C, I_{GM} = 1.5A, $t_r \le 0.5$ µs		150	A/µs

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**VALUES**	**UNITS**
Maximum junction operating temperature range	T_J		- 40 to 125	°C
Maximum storage temperature range	T_{Stg}		- 40 to 150	
Maximum thermal resistance, junction to ca se per junction	R_{thJC}	DC operation	0.28	°C/W
Maximum thermal resistance, case to heatsink per module	R_{thCS}	Mounting surface, smooth , flat and greased	0.077	
Mounting torque ± 10 % — AAP to heatsink, M6 / busbar to AAP, M5		A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound. Lubricated threads.	4	N.m
Approximate weight			120	g
			4.23	oz.
Case style			ADD-A-PAK	

ORDERING INFORMATION TABLE

Device code

NK	T	90	/	16	A
①	②	③		④	⑤

1 - Module type
2 - Circuit configuration
3 - Current rating: $I_{T(AV)}$
4 - Voltage code x 100 = V_{RRM}
5 - Assembly type,"A" for soldering type

Fig.1 Peak On-state Voltage vs. Peak On-state Current

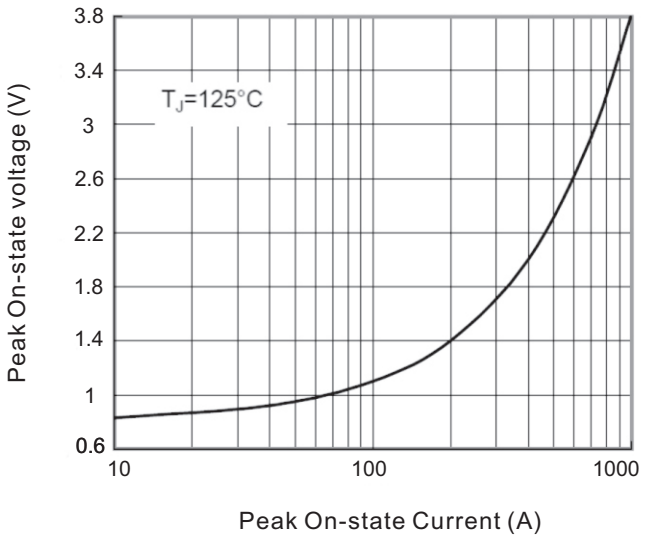


Fig.2 Max. Thermal Impedance (Junction To case) Vs. Time

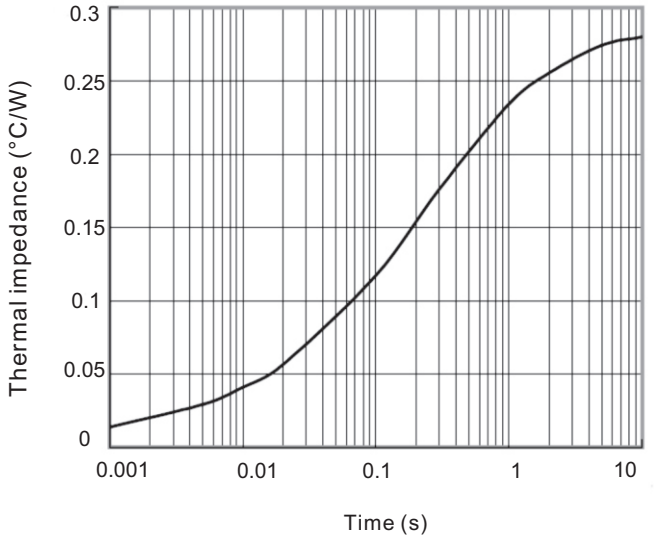


Fig.3 Power Dissipation Vs. Average On-state Current

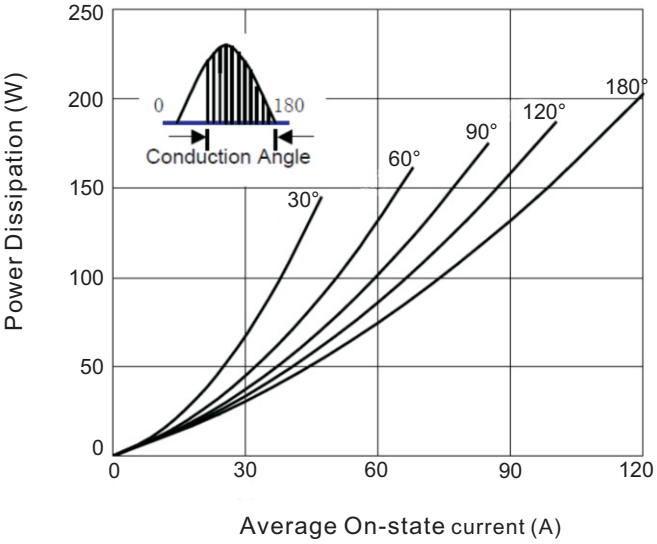


Fig.4 Case Temperature Vs. Average On-state Current

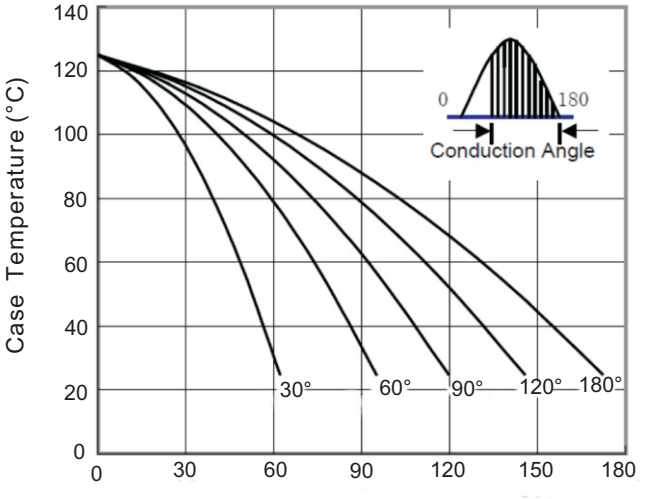


Fig.5 Surge On-state Current Vs. Cycles

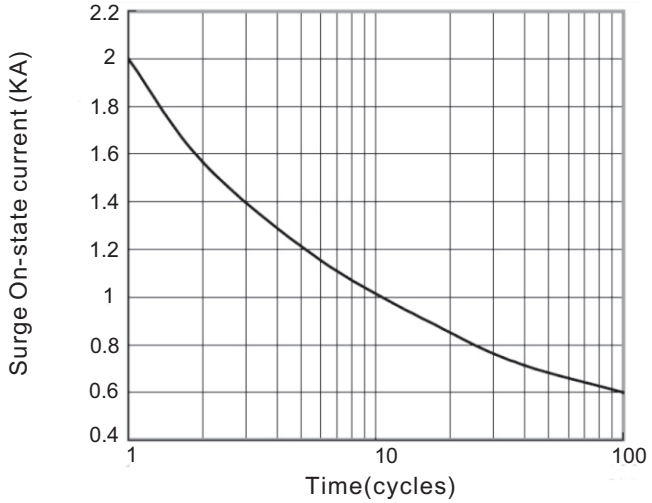


Fig.6 Gate characteristics